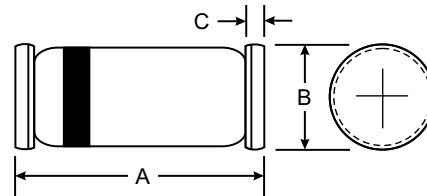


Features

- Ideal for Fast Logic Applications
- Ultra Fast Switching
- High Reliability
- High Conductance

Mechanical Data

- Case: MiniMELF, Glass
- Terminals: Solderable per MIL-STD-202, Method 208
- Marking: Cathode Band Only
- Polarity: Cathode Band
- Weight: 0.05 grams (approx.)



MiniMELF		
Dim	Min	Max
A	3.30	3.70
B	1.30	1.60
C	0.28	0.50
All Dimensions in mm		

Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	LL4150	Unit
Non-Repetitive Peak Reverse Voltage @ $5.0\mu\text{A}$	V_{RM}	75	V
Peak Repetitive Reverse Voltage	V_{RRM}	50	V
Working Peak Reverse Voltage	V_{RWM}		
DC Blocking Voltage	V_R		
RMS Reverse Voltage	$V_{R(RMS)}$	35	V
Forward Continuous Current (Note 1)	I_{FM}	400	mA
Average Rectified Output Current (Note 1)	I_O	200	mA
Repetitive Peak Forward Current (Note 1)	I_{FRM}	600	mA
Non-Repetitive Peak Forward Surge Current @ $t \leq 1.0\text{s}$ @ $t = 1.0\mu\text{s}$	I_{FSM}	1.0 4.0	A
Power Dissipation (Note 1)	P_d	500	mW
Thermal Resistance, Junction to Ambient Air (Note 1)	$R_{\theta JA}$	300	K/W
Operating and Storage Temperature Range	T_J, T_{STG}	-65 to +200	$^\circ\text{C}$

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
Maximum Forward Voltage Drop	V_{FM}	0.54 0.66 0.76 0.82 0.87	0.62 0.74 0.86 0.92 1.00	V	$I_F = 1.0\text{mA}$ $I_F = 10\text{mA}$ $I_F = 50\text{mA}$ $I_F = 100\text{mA}$ $I_F = 200\text{mA}$
Maximum Peak Reverse Current	I_{RM}	—	100	nA μA	$T_A = 25^\circ\text{C}$ $T_A = 150^\circ\text{C}$
Junction Capacitance	C_j	—	2.5	pF	$V_R = 0\text{V}, f = 1.0\text{MHz}$
Reverse Recovery Time	t_{rr}	—	4.0	ns	$I_F = I_R = 200\text{mA}$, $I_{rr} = 0.1 \times I_R, R_L = 100\Omega$
Forward Recovery Time	t_{fr}	—	10	ns	$I_F = 200\text{mA}, V_{FR} = 1.0\text{V}$

Note: 1. Valid provided that electrodes are kept at ambient temperature.